

HAT1021R

Silicon P Channel Power MOS FET
High Speed Power Switching

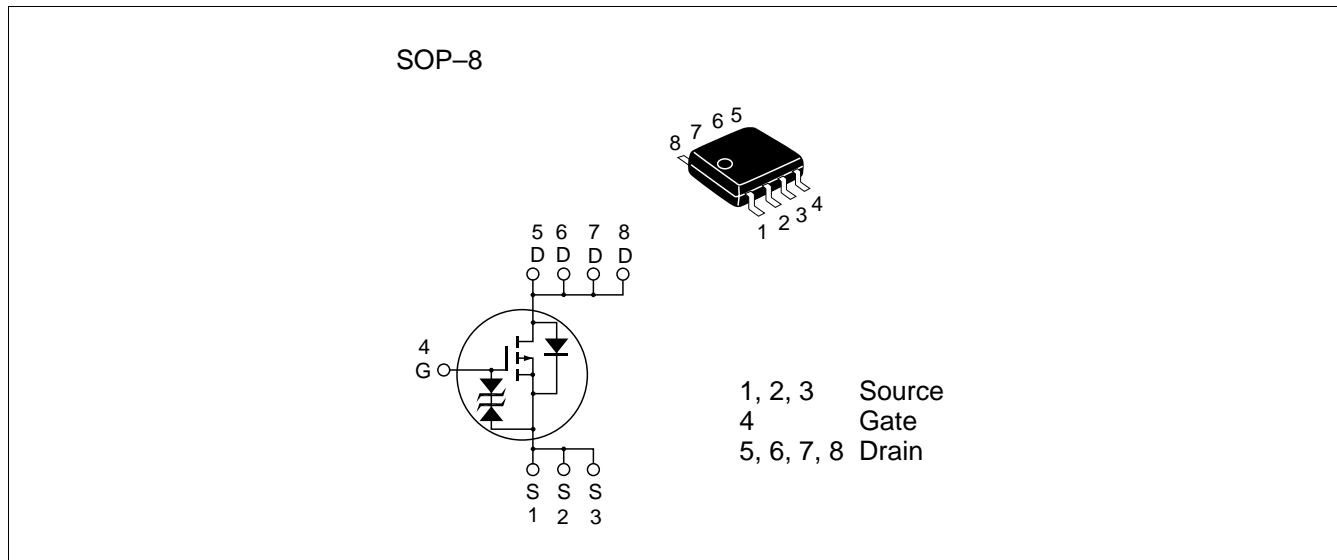
HITACHI

ADE-208-475 D (Z)
5th. Edition
February 1999

Features

- Low on-resistance
- Capable of 2.5 V gate drive
- Low drive current
- High density mounting

Outline



Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	- 20	V
Gate to source voltage	V_{GSS}	± 10	V
Drain current	I_D	- 5.5	A
Drain peak current	$I_{D(pulse)}$ ^{Note1}	- 44	A
Body-drain diode reverse drain current	I_{DR}	- 5.5	A
Channel dissipation	Pch ^{Note2}	2.5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

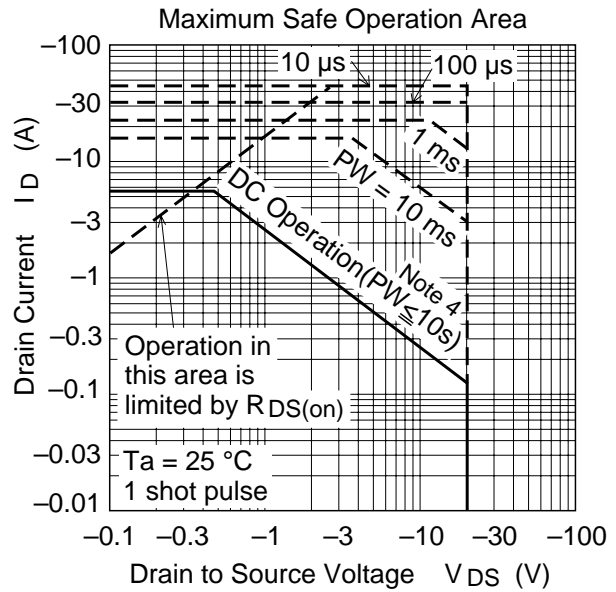
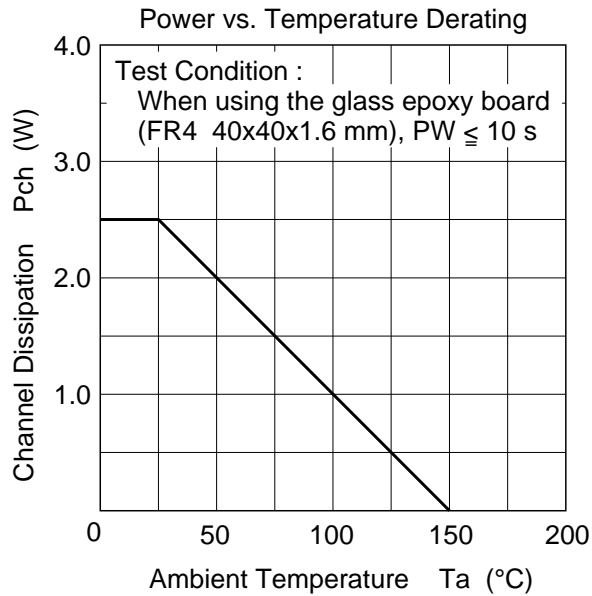
Note: 1. $PW \leq 10\mu s$, duty cycle $\leq 1\%$
 2. When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), $PW \leq 10s$

Electrical Characteristics (Ta = 25°C)

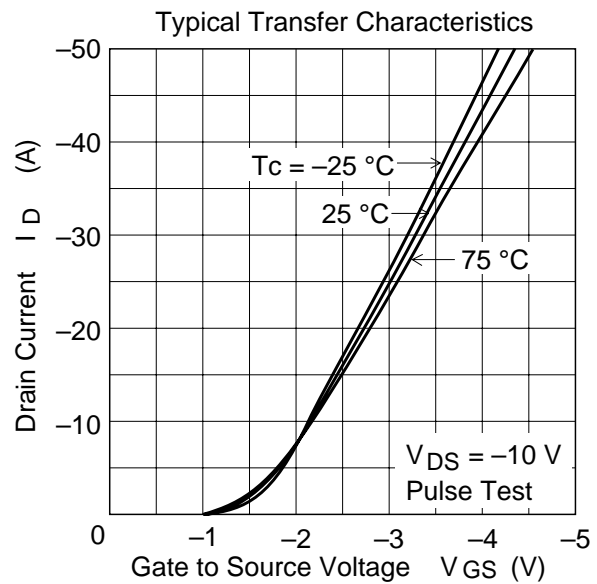
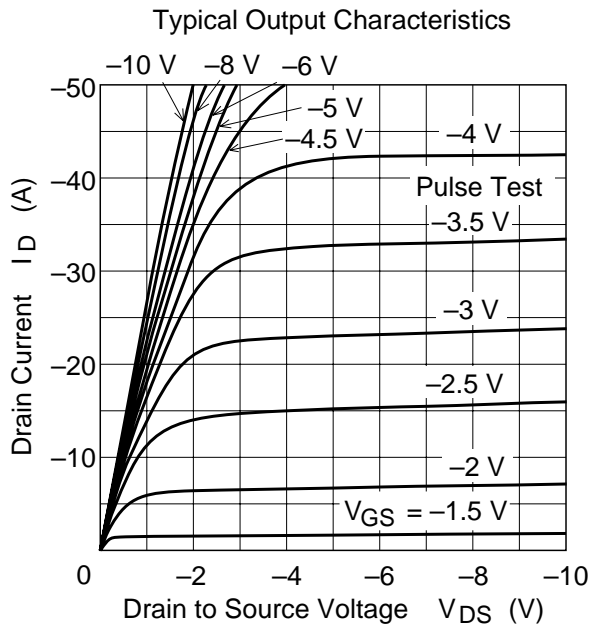
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	- 20	—	—	V	$I_D = -10\text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 10	—	—	V	$I_G = \pm 100\ \mu A$, $V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 8\text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	- 10	μA	$V_{DS} = -20\text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	- 0.5	—	- 1.5	V	$V_{DS} = -10\text{ V}$, $I_D = -1\text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	0.048	0.060	Ω	$I_D = -3\text{ A}$, $V_{GS} = -4\text{ V}$ ^{Note3}
	$R_{DS(on)}$	—	0.065	0.085	Ω	$I_D = -3\text{ A}$, $V_{GS} = -2.5\text{ V}$ ^{Note3}
Forward transfer admittance	$ y_{fs} $	6	9.5	—	S	$I_D = -3\text{ A}$, $V_{DS} = -10\text{ V}$ ^{Note3}
Input capacitance	Ciss	—	1200	—	pF	$V_{DS} = -10\text{ V}$
Output capacitance	Coss	—	630	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	—	200	—	pF	f = 1MHz
Turn-on delay time	$t_{d(on)}$	—	20	—	ns	$V_{GS} = -4\text{ V}$, $I_D = -3\text{ A}$
Rise time	t_r	—	120	—	ns	$V_{DD} \cong -10\text{ V}$
Turn-off delay time	$t_{d(off)}$	—	175	—	ns	
Fall time	t_f	—	140	—	ns	
Body-drain diode forward voltage	V_{DF}	—	- 0.9	- 1.4	V	$I_F = -5.5\text{ A}$, $V_{GS} = 0$ ^{Note3}
Body-drain diode reverse recovery time	t_{rr}	—	65	—	ns	$I_F = -5.5\text{ A}$, $V_{GS} = 0$ $diF/dt = 20\text{ A}/\mu s$

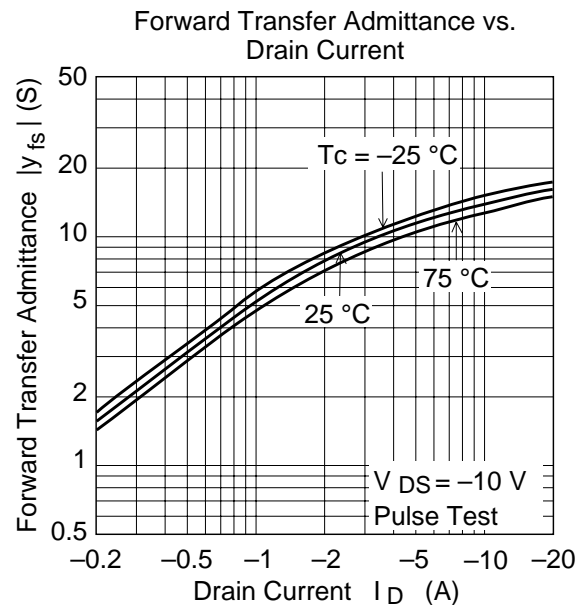
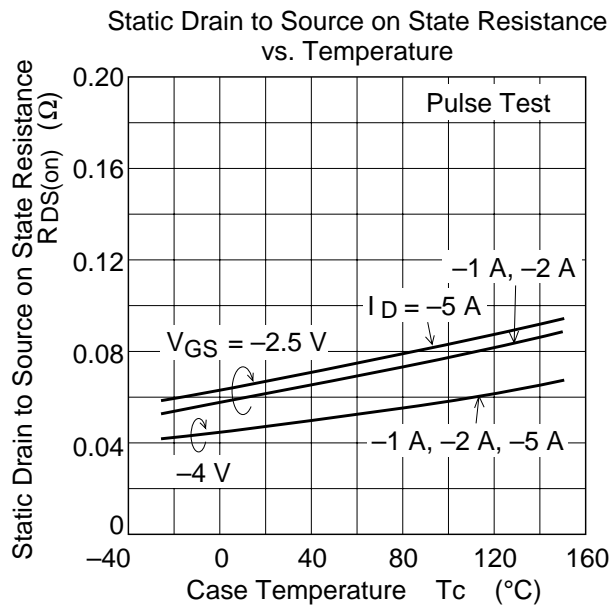
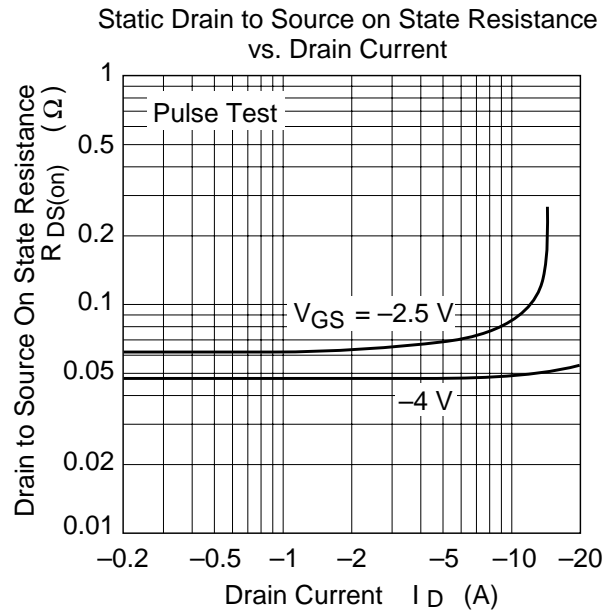
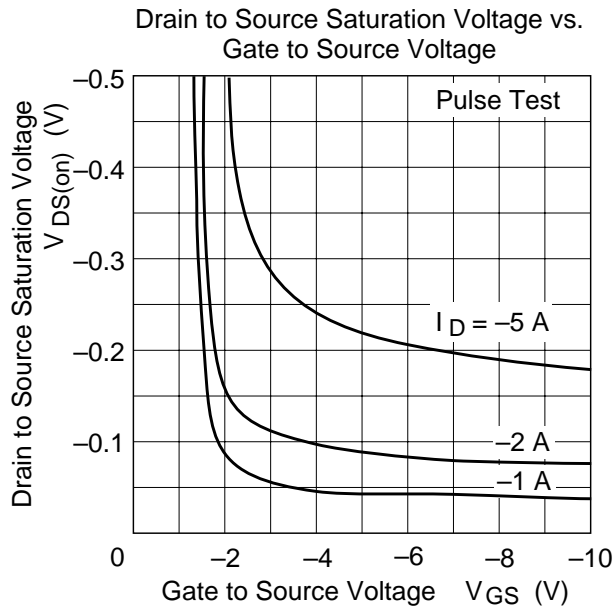
Note: 3. Pulse test

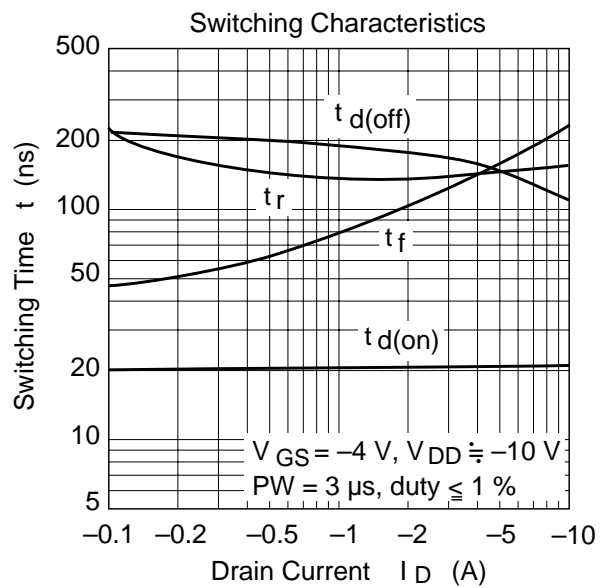
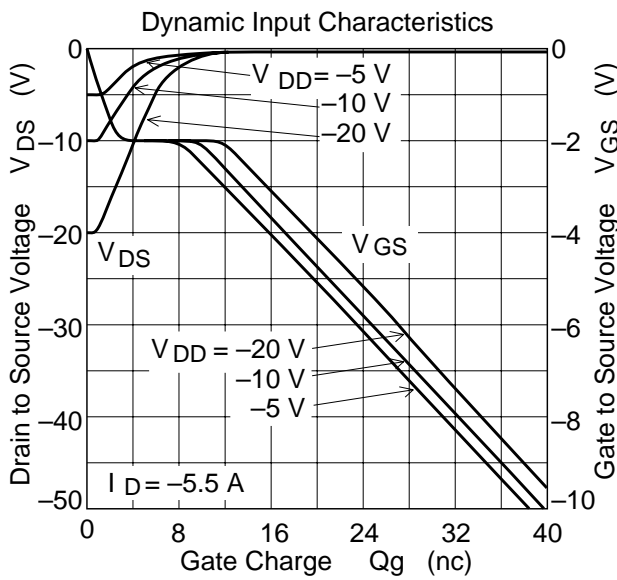
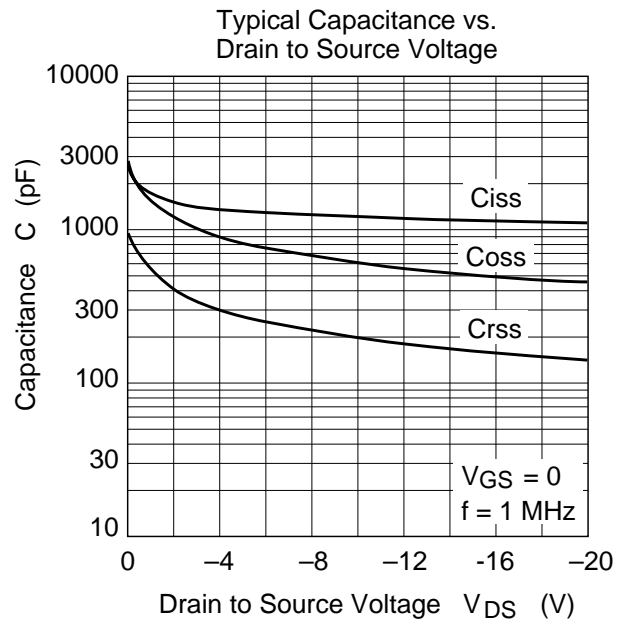
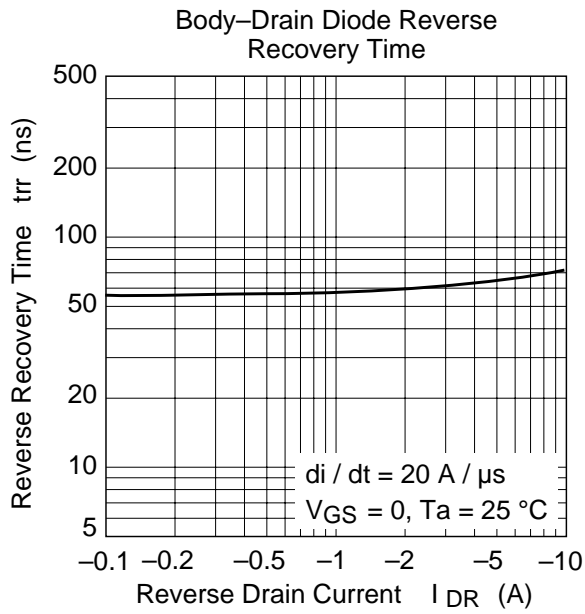
Main Characteristics

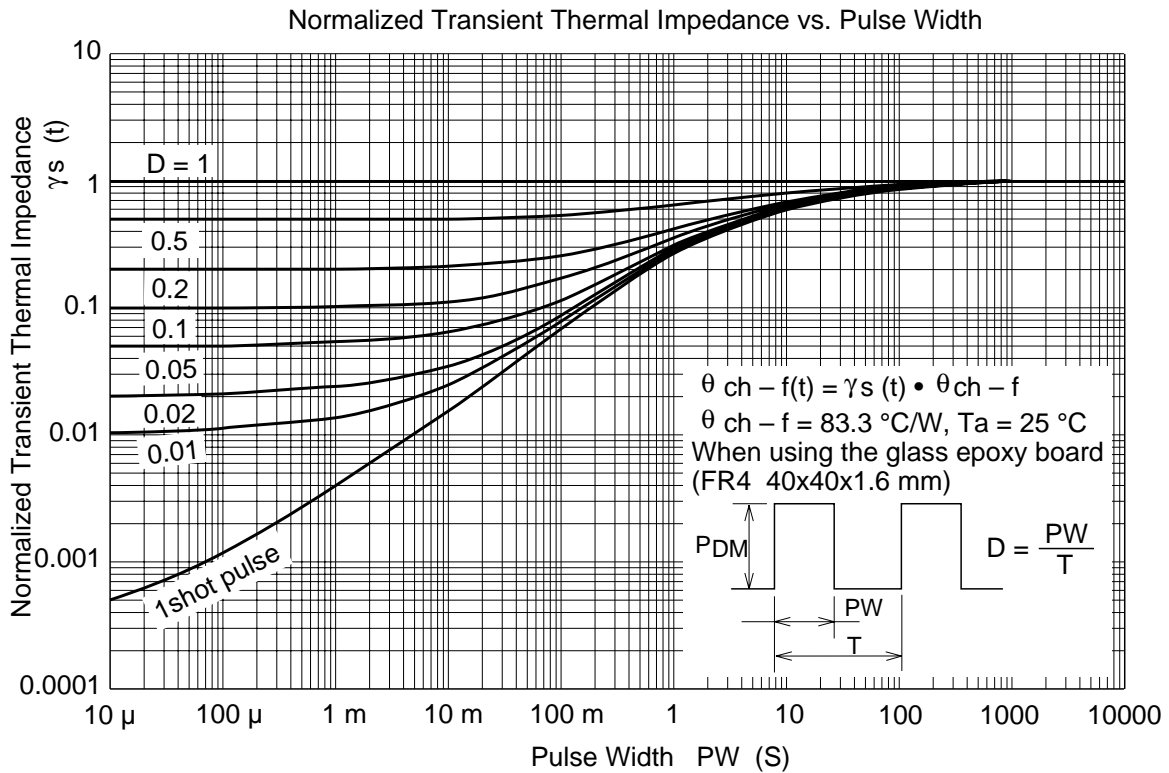
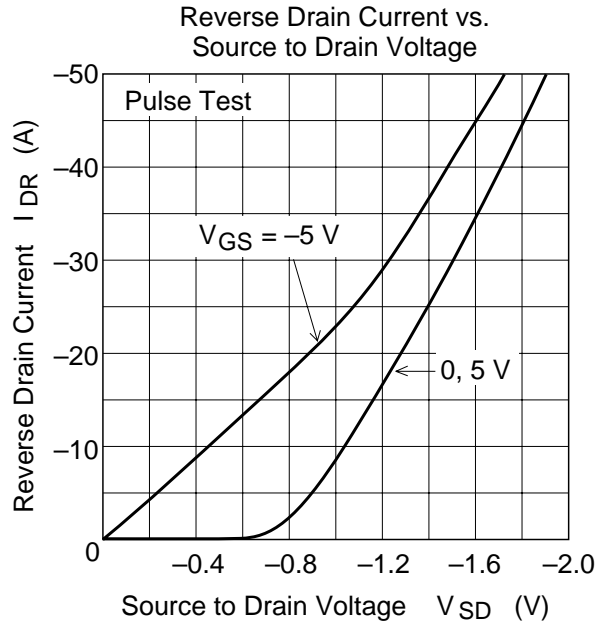


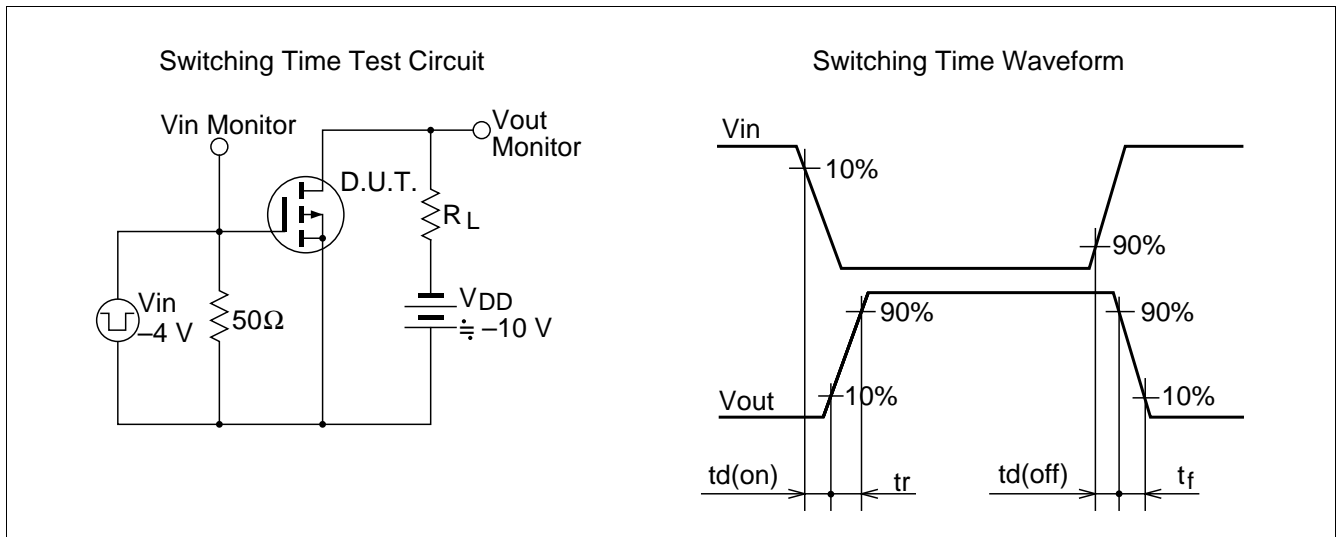
Note 4 :
When using the glass epoxy board (FR4 40 x 40 x 1.6 mm)







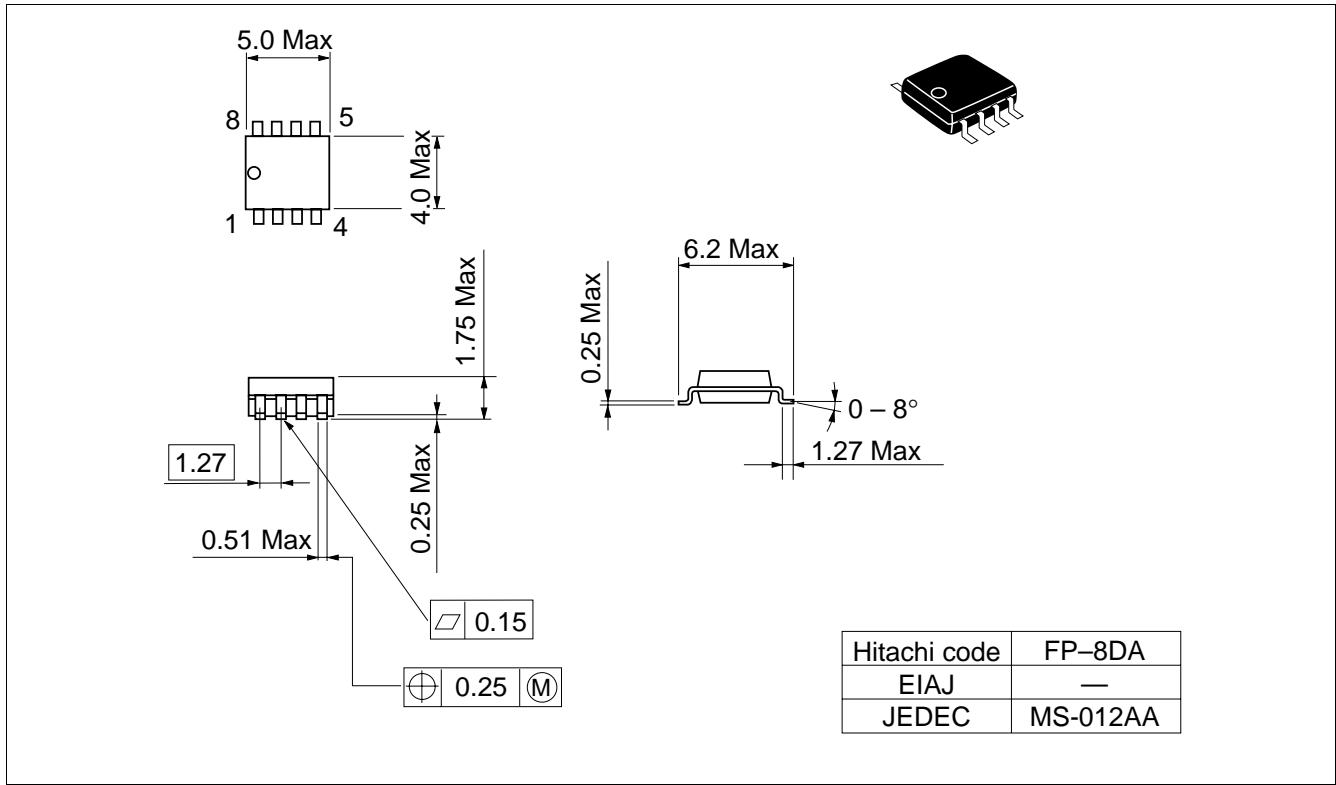




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Package Dimensions

Unit: mm



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